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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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#### DATA SHEET

# MOS FIELD EFFECT TRANSISTOR

# 2SK3353

### SWITCHING **N-CHANNEL POWER MOS FET**

#### DESCRIPTION

RENESAS

The 2SK3353 is N-channel MOS Field Effect Transistor designed for high current switching applications.

#### **FEATURES**

- Super low on-state resistance:
- $R_{DS(on)1} = 9.5 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, \text{ ID} = 41 \text{ A})$
- $R_{DS(on)2} = 14 \text{ m}\Omega \text{ MAX.} (V_{GS} = 4 \text{ V}, \text{ ID} = 41 \text{ A})$
- Low Ciss: Ciss = 4650 pF TYP.
- Built-in gate protection diode

#### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}C$ )

Drain to Source Voltage (Vgs = 0 V)	VDSS	60	V
Gate to Source Voltage ( $V_{DS} = 0 V$ )	Vgss	±20	V
Drain Current (DC) (Tc = $25^{\circ}$ C)	D(DC)	±82	А
Drain Current (pulse) Note1	D(pulse)	±328	А
Total Power Dissipation (Tc = 25°C)	Ρτ	95	W
Total Power Dissipation ( $T_A = 25^{\circ}C$ )	Ρτ	1.5	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	las	45	А
Single Avalanche Energy Note2	Eas	202	mJ

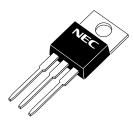
#### **Notes 1.** PW $\leq$ 10 $\mu$ s, Duty cycle $\leq$ 1%

**2.** Starting T<sub>ch</sub> = 25°C, V<sub>DD</sub> = 30 V, R<sub>G</sub> = 25  $\Omega$ , V<sub>GS</sub> = 20  $\rightarrow$  0 V

#### **ORDERING INFORMATION** PART NUMBER PACKAGE 2SK3353 TO-220AB 2SK3353-S TO-262 2SK3353-ZJ TO-263 TO-220SMD<sup>Note</sup> 2SK3353-Z

Note TO-220SMD package is produced only in Japan

(TO-220AB)



(TO-262)



(TO-263, TO-220SMD)



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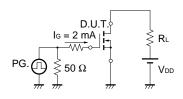
#### ELECTRICAL CHARACTERISTICS (TA = 25°C)

Characteristics	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Zero Gate Voltage Drain Current	IDSS	Vds = 60 V, Vgs = 0 V			10	μA
Gate Leakage Current	lgss	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±10	μA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 41 A	30	50		S
Drain to Source On-state Resistance	RDS(on)1	$V_{GS} = 10 V$ , $I_{D} = 41 A$		7.5	9.5	mΩ
	RDS(on)2	$V_{GS} = 4V$ , $I_D = 41 A$		10.5	14	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V		4650		pF
Output Capacitance	Coss	Vgs = 0 V		780		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		380		pF
Turn-on Delay Time	td(on)	Vdd = 30 V, Id = 41 A		100		ns
Rise Time	tr	Vgs = 10 V		1550		ns
Turn-off Delay Time	td(off)	Rg = 10 Ω		280		ns
Fall Time	tr			420		ns
Total Gate Charge	QG	V <sub>DD</sub> = 48 V		90		nC
Gate to Source Charge	Q <sub>GS</sub>	Vgs = 10 V		14		nC
Gate to Drain Charge	Qgd	ID = 82 A		24		nC
Body Diode Forward Voltage	VF(S-D)	IF = 82 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 82 A, VGS = 0 V		60		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/µs		110		nC

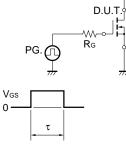
#### TEST CIRCUIT 1 AVALANCHE CAPABILITY

# $PG. \square \leq 50 \Omega$ $V_{GS} = 20 \rightarrow 0V$ $V_{DD}$ $V_{$

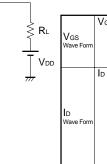
#### TEST CIRCUIT 3 GATE CHARGE

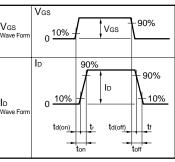


# TEST CIRCUIT 2 SWITCHING TIME

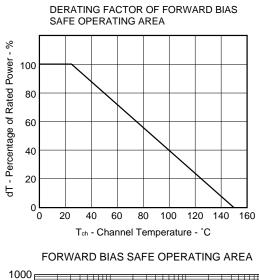


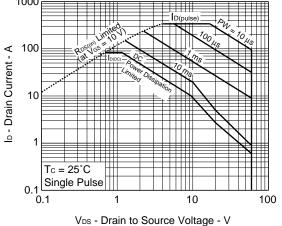
τ = 1 μsDuty Cycle ≤ 1%

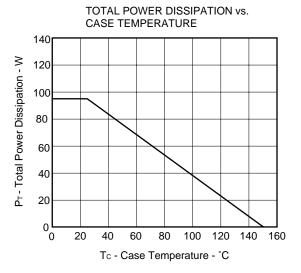




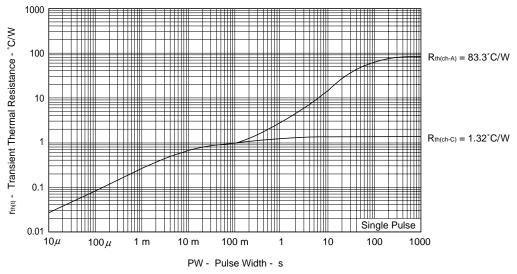
#### TYPICAL CHARACTERISTICS (TA = 25°C)



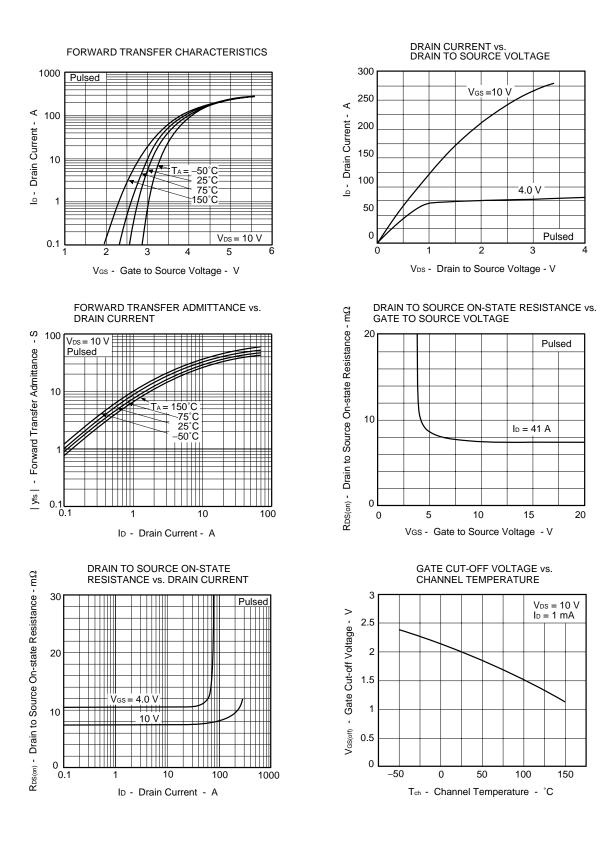




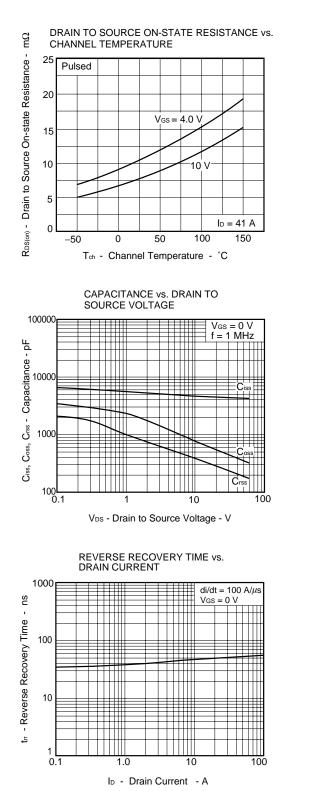
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

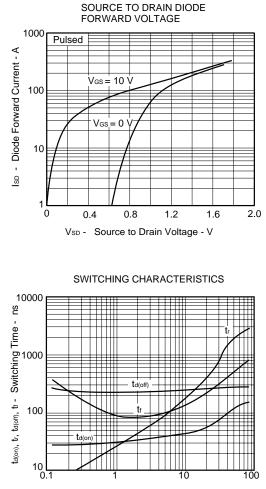


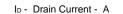
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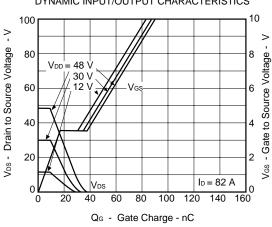




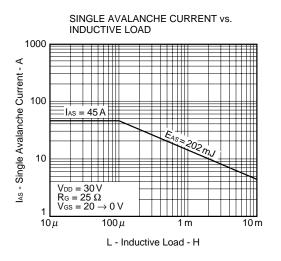


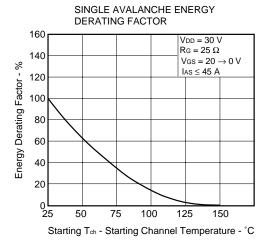
10

100



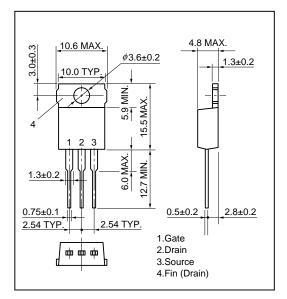
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



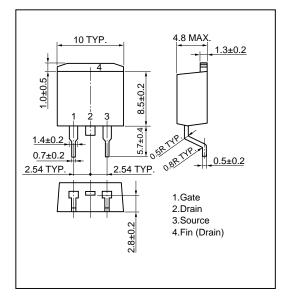


#### ★ PACKAGE DRAWINGS (Unit: mm)

#### 1) TO-220AB(MP-25)

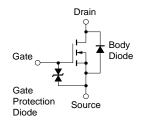


#### 3) TO-263 (MP-25ZJ)

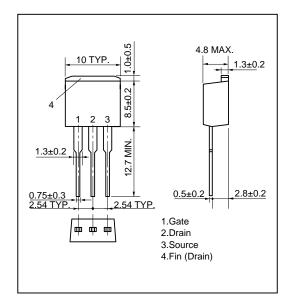


Remark

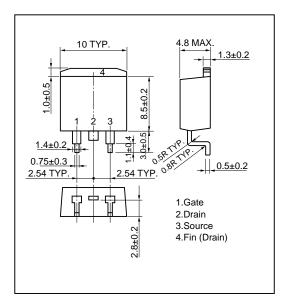
#### EQUIVALENT CIRCUIT



#### 2) TO-262(MP-25 Fin Cut)



4) TO-220SMD (MP-25Z)<sup>Note</sup>



Note This package is produced only in Japan.

The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

Data Sheet D14130EJ4V0DS

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